



#### P-CHANNEL ENHANCEMENT MODE MOSFET

## **Product Summary**

V <sub>(BR)DSS</sub>	R <sub>DS(on) max</sub>	<b>Ι</b> <u></u> Τ <sub>A</sub> = +25°C
2014	70mΩ@ V <sub>GS</sub> = -10V	-3.8A
-30V	120mΩ@ V <sub>GS</sub> =-4.5V	-3.0A

## **Description and Applications**

This new generation MOSFET has been designed to minimize the onstate resistance (R<sub>DS(on)</sub>) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

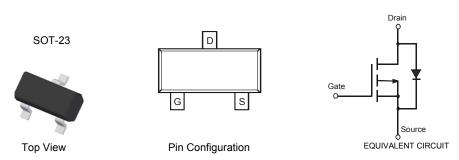
- Power management functions
- Analog Switch
- Load Switch
- **Boost Switch**

### Features and Benefits

- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

### Mechanical Data

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin annealed over Copper leadframe. Solderable per MIL-STD-202, Method 208
- Terminal Connections: See Diagram
- Weight: 0.008 grams (approximate)



### Ordering Information (Note 4)

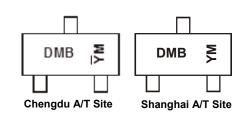
Part Number	Case	Packaging
DMP3098L-7	SOT23	3000/Tape & Reel

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. 2. See http://www.diodes.com/quality/lead\_free.html com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free,

"Green" and Lead-free. 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html

## Marking Information



DMB = Product Type Marking Code YM = Date Code Marking for SAT (Shanghai Assembly/ Test site) YM = Date Code Marking for CAT (Chengdu Assembly/ Test site) Y or  $\overline{Y}$  = Year (ex: A = 2013) M = Month (ex: 9 = September)

Date Code Key

Notes:

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Year	2008		2009	2010		2011	2012		2013	2014		2015
Code	V		W	Х		Y	Z		А	В		С
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	Ν	D



# Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteris		Symbol	Value	Units	
Drain-Source Voltage		V <sub>DSS</sub>	-30	V	
Gate-Source Voltage		V <sub>GSS</sub>	±20	V	
Drain Current (Note 5) V <sub>GS</sub> = -10V	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C		-3.8 -2.9	A	
Pulsed Drain Current (Note 6)			I <sub>DM</sub>	-11	А

# **Thermal Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Units
Total Power Dissipation (Note 5)	PD	1.08	W
Thermal Resistance, Junction to Ambient @T <sub>A</sub> = +25°C (Note 5)	$R_{ heta JA}$	115	°C/W
Operating and Storage Temperature Range	T <sub>J,</sub> T <sub>STG</sub>	-55 to +150	°C

## Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

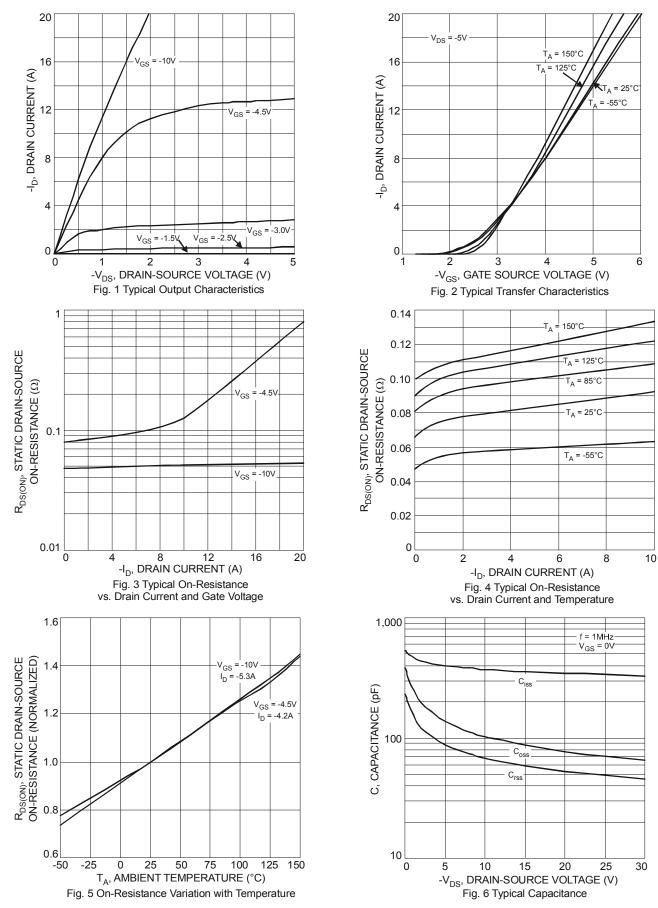
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)	Cymbol		- JP	Inux	Unit		
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	-30		_	V	V <sub>GS</sub> = 0V, I <sub>D</sub> = -250µA	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>		_	-800	nA	$V_{DS} = -30V, V_{GS} = 0V$	
Gate-Source Leakage	I <sub>GSS</sub>		_	±100	nA	V <sub>GS</sub> = ±20V, V <sub>DS</sub> = 0V	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V <sub>GS(th)</sub>	-1.0	-1.8	-2.1	V	$V_{DS} = V_{GS}, I_D = -250 \mu A$	
Static Drain-Source On-Resistance			56	70	mΩ	V <sub>GS</sub> = -10V, I <sub>D</sub> = -3.8A	
	R <sub>DS</sub> (ON)		98	120	11152	$V_{GS}$ = -4.5V, $I_{D}$ = -3.0A	
Forward Transfer Admittance	Y <sub>fs</sub>		3.6	_	S	$V_{DS} = -5V, I_D = -2.7A$	
Diode Forward Voltage (Note 6)	V <sub>SD</sub>			-1.26	V	$V_{GS} = 0V, I_{S} = -2.7A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss		336	1008	pF		
Output Capacitance	Coss		70	210	pF	V <sub>DS</sub> = -25V, V <sub>GS</sub> = 0V, f = 1.0MHz	
Reverse Transfer Capacitance	C <sub>rss</sub>		49	147	pF		
Gate Resistance	R <sub>G</sub>		4.6	—	Ω	$V_{GS}$ = 0V, $V_{DS}$ = 0V, f = 1MHz	
SWITCHING CHARACTERISTICS (Note 8)							
Total Gate Charge	Qg	—	4.0	8.0		V <sub>DS</sub> = -15V, V <sub>GS</sub> = -4.5V, I <sub>D</sub> = -3.8A	
	-	_	7.8	_	nC		
Gate-Source Charge	Q <sub>gs</sub>		1.0	_		V <sub>DS</sub> = -15V, V <sub>GS</sub> = -10V, I <sub>D</sub> = -3.8A	
Gate-Drain Charge	Q <sub>gd</sub>		2.5	—		ID3.6A	
Turn-On Delay Time	t <sub>d(on)</sub>	_	6.0	12.0			
Rise Time	tr		5.0	10.0		V <sub>DS</sub> = -15V, V <sub>GS</sub> = -10V,	
Turn-Off Delay Time	t <sub>d(off)</sub>	_	17.6	35.2	ns	$I_{D} = -1A, R_{G} = 6.0\Omega$	
Fall Time	t <sub>f</sub>	_	9.5	19.0			

Notes: 5. Device mounted on FR-4 PCB on 2 oz., 0.5 in.<sup>2</sup> copper pads and t  $\leq$ 5 sec.

6. Pulse width ≤10μS, Duty Cycle ≤1%.
7. Short duration pulse test used to minimize self-heating effect.
8. Guaranteed by design. Not subject to production testing.

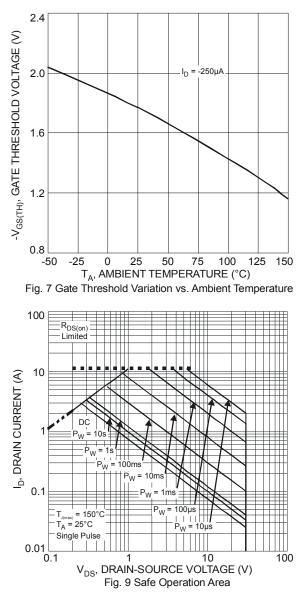


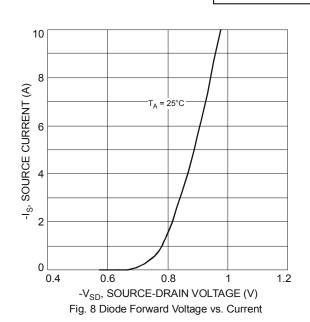
## DMP3098L



DMP3098L Document number: DS31447 Rev. 8 - 2 Downloaded from Arrow.com.

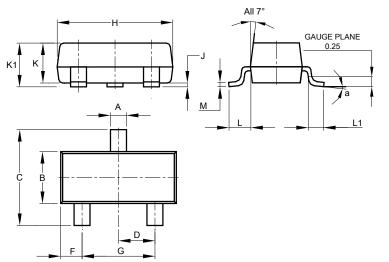






# **Package Outline Dimensions**

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.

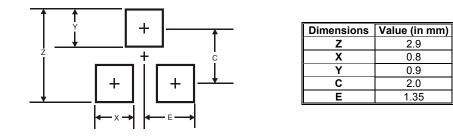


SOT23							
Dim	Min	Max	Тур				
Α	0.37	0.51	0.40				
в	1.20	1.40	1.30				
C	2.30	2.50	2.40				
D	0.89	1.03	0.915				
F	0.45	0.60	0.535				
G	1.78	2.05	1.83				
Н	2.80	3.00	2.90				
<b>ر</b>	0.013	0.10	0.05				
κ	0.890	1.00	0.975				
K1	0.903	1.10	1.025				
L	0.45	0.61	0.55				
L1	0.25	0.55	0.40				
М	0.085	0.150	0.110				
α	8°						
All Dimensions in mm							



# Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



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